Course Specifications
Valid as from the academic year 2020-2021

Micro- and Nanophotonic Semiconductor Devices (E030782)

Due to Covid 19, the education and evaluation methods may vary from the information displayed in the schedules and course details. Any changes will be communicated on Ufora.

Course size
(nominal values, actual values may depend on programme)

Credits 4.0  Study time 120 h  Contact hrs 60.0 h

Course offerings and teaching methods in academic year 2020-2021

A (semester 2)  English  Gent

- project: 5.0 h
- seminar: coached exercises: 5.0 h
- lecture: 30.0 h

Lecturers in academic year 2020-2021

Van Thourhout, Dries  TW05  lecturer-in-charge

Offered in the following programmes in 2020-2021

- Bridging Programme European Master of Science in Photonics
- European Master of Science in Photonics

Offering 4  A

Teaching languages
English

Keywords
Photonics, Semiconductor, Heterojunctions, nanotechnology, Sources, detectors, modulators, quantum dot, quantum wire

Position of the course

The student will acquire an advanced theoretical framework (mathematical and quantum-mechanical tools) to design optoelectronic devices. He will get insight in the band structures of semiconductors and how they change in structures with reduced dimensions. He/she will get insights in the newest technologies to develop novel devices for the future. He/she will learn the operation principles of a large set of photonic devices such as detectors, light sources, modulators and others. The course will be a solid base to understand the operation of micro and nanophotonic semiconductor devices of today, and will allow students to design novel devices for future photonic applications.

Contents

- The course is divided into three arts: a) Physics of semiconductors for photonic applications b) Photonic Semiconductor Devices and c) Micro and nano-technologies.
  - Basic properties of semiconductors: Introduction, Comparative study of whole set of semiconductors
  - Electron wave functions in semiconductors: dispersion relations
  - Heterostructures: Lattice matched and pseudomorphic structures, Quantum confinement
  - Phonons: optical, acoustical; transverse, longitudinal
  - Optical transitions: Fermi's Golden Rule, direct and indirect absorption processes, free carrier absorption, phonon absorption
  - Crystal- and epitaxial growth: Crystal Growth, Epitaxial Growth
  - Definition of nano structures: bottom up and top down technologies
  - Sources: LED, Lasers (Gain, non-parabolic effects, strain effects)
  - Detectors: PIN, Avalanche, SiGe, Infrared, Metal-Schottky, Quantum Well IR, Quantum Dot IR, Thermal, Seebeck detectors

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* Modulators: Electro-absorption, quantum confined stark effect, electro optic modulation
* Advanced fotonic semiconductor components: Quantum dots, wires, quantum cascade lasers...

Initial competences
- Basic knowledge quantum physics
- Basic knowledge semiconductor physics

Final competences
1. Have insight in the operation of advanced photonic semiconductor components.
2. Being able to design basic semiconductor components.
3. Understand some advanced techniques for the fabrication of photonic semiconductor components.

Conditions for credit contract
Access to this course unit via a credit contract is determined after successful competences assessment

Conditions for exam contract
This course unit cannot be taken via an exam contract

Teaching methods
- Lecture, project, seminar: coached exercises

Learning materials and price
- Book “Physics of Optoelectronic Devices” (see below) - available electronically through UGent library

References
- “Essentials of Semiconductor Physics”, Tom Wenckebach
- “Physics of Optoelectronic Devices”, Shun Lien Chuang

Course content-related study coaching

Evaluation methods
- end-of-term evaluation and continuous assessment

Examination methods in case of periodic evaluation during the first examination period
- Oral examination

Examination methods in case of periodic evaluation during the second examination period
- Oral examination

Examination methods in case of permanent evaluation
- Oral examination, report

Possibilities of retake in case of permanent evaluation
- examination during the second examination period is possible in modified form

Extra information on the examination methods
- During examination period: written open-book exam with oral defense; written open-book exam - problems
- During semester: graded project reports.

Calculation of the examination mark
- Project at the beginning of second half of semester. The final report of this assignment will be evaluated during an oral discussion. A partial exemption can be obtained for a maximum of 35% of the grand total. At the end of the semester - an oral examination, prepared in a written way with a minimum of 65% of the grand total with open book will be organized.

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